





100V NPN LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT89

Features

- BV_{CEO} > 100V
- I_C = 4.5A high Continuous Current
- I_{CM} = 10A Peak Pulse Current
- $R_{CE(sat)} = 31m\Omega$ for a low equivalent On-Resistance
- Low saturation voltage V_{CE(sat)} < 60mV @ I_C = 1A
- h_{FE} specified up to 10A for high current gain hold up
- Lead-Free Finish; RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

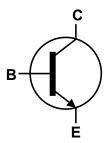
- Case: SOT89
- Case material: molded plastic. "Green" molding compound.
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208
 S
- Weight: 0.05 grams (Approximate)

Applications

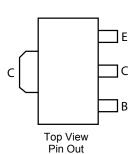
- Motor driving
- Line switching
- · High side switches
- Subscriber line interface cards (SLIC)



Top View



Device Symbol



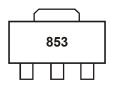
Ordering Information (Note 4)

Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
7XTN20117TA	853	7	12	1 000

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

Marking Information



853 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V_{CBO}	200	V
Collector-Emitter Voltage	V _{CEO}	100	V
Emitter-Base Voltage	V_{EBO}	7	V
Continuous Collector Current	Ic	4.5	Α
Peak Pulse Current	I _{CM}	10	А

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	P _D	1.5	W
Linear derating factor	10	12	mW/°C
Power Dissipation (Note 6)	В	2.1	W
Linear derating factor	P _D	16.8	mW/°C
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	83	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	$R_{\theta JA}$	60	°C/W
Thermal Resistance, Junction to Ambient (Note 7)	R _{0JL}	3.23	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

ESD Ratings (Note 8)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

Notes:

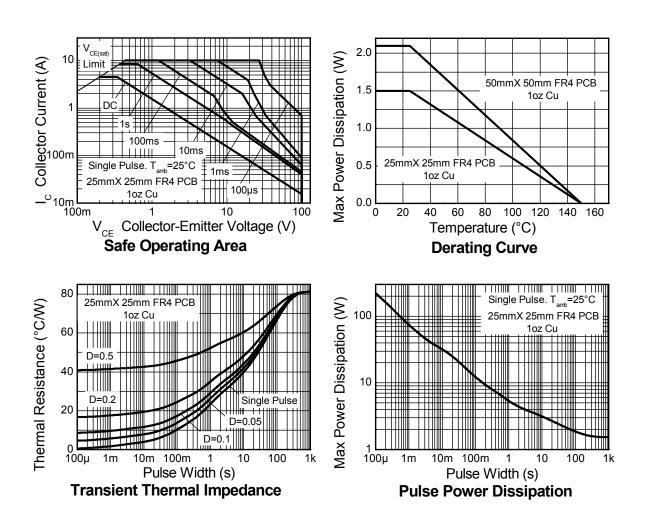
- 5. For a device surface mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; device measured when operating in steady state condition.
- Refer to JEDEC specification JESD22-A114 and JESD22-A115.

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Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

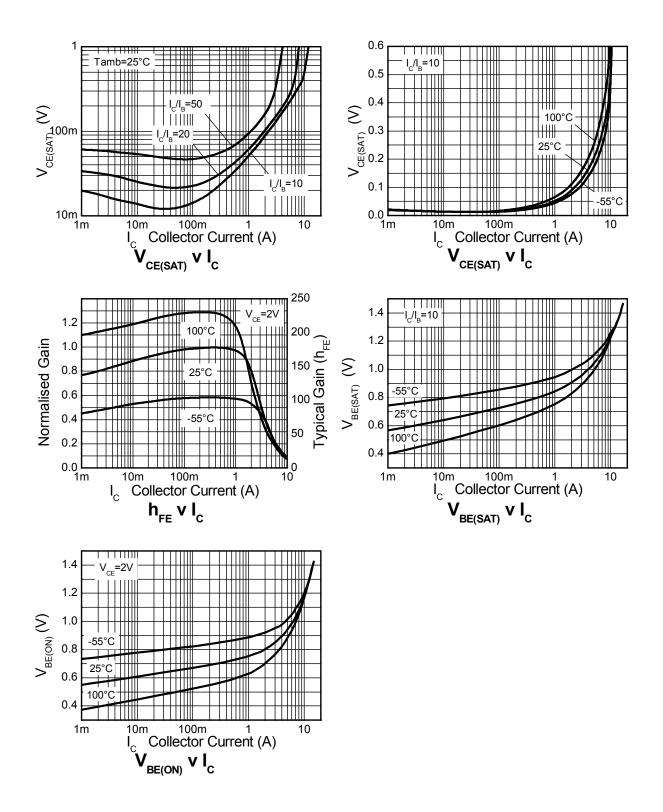
Characteristic	Symbol	Min	Тур.	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	BV _{CBO}	200	235	-	V	$I_{C} = 100 \mu A$
Collector-Emitter Breakdown Voltage (Notes 9)	BV _{CER}	200	235	-	V	$I_C = 1\mu A, R_B \le 1k\Omega$
Collector-Emitter Breakdown Voltage (Notes 9)	BV _{CEO}	100	115	-	V	I _C = 1mA
Emitter-Base Breakdown Voltage	BV _{EBO}	7	8.1	-	V	I _E = 100μA
Collector Cutoff Current	I _{CBO}	-	<1 -	50 500	nA nA	V _{CB} = 150V V _{CB} = 150V, T _A = +100°C
Collector Cutoff Current	I _{CER} R≤1kΩ	-	<1 -	100 500	nA nA	V _{CB} = 150V V _{CB} = 150V, T _A = +100°C
Emitter Cutoff Current	I _{EBO}	-	<1	10	nA	V _{EB} = 6V
	h _{FE}	100	230	-	-	I _C = 10mA, V _{CE} = 2V
DC Current Transfer Static Potic (Notes 0)		100	200	300		$I_C = 2A$, $V_{CE} = 2V$
DC Current Transfer Static Ratio (Notes 9)		30	60	-		$I_{C} = 5A, V_{CE} = 2V$
		10	20	-		$I_C = 10A, V_{CE} = 2V$
		-	20	30		$I_C = 100 \text{mA}, I_B = 5 \text{mA}$
Collector-Emitter Saturation Voltage (Notes 9)	V _{CE(sat)}	-	45	60	mV	I _C = 1A, I _B = 100mA
Collector-Emitter Saturation Voltage (Notes 9)		-	85	115	IIIV	$I_C = 2A$, $I_B = 100mA$
		-	155	195		$I_C = 5A$, $I_B = 500mA$
Base-Emitter Saturation Voltage (Notes 9)	$V_{BE(sat)}$	-	1000	1100	mV	$I_C = 5A$, $I_B = 500mA$
Base-Emitter Turn-on Voltage (Notes 9)	V _{BE(on)}	-	900	1000	mV	$I_{C} = 5A, V_{CE} = 2V$
Transitional Frequency	f _T	-	130	-	MHz	I _C = 100mA, V _{CE} = 10V, f = 50MHz
Output Capacitance	C_{obo}	-	26	-	pF	V _{CB} = 10V, f = 1MHz,
Switching Time	t _{on}		41		ns	$V_{CC} = 10V, I_{C} = 1A,$
Switching Time	t _{off}	_	1010	_	115	$I_{B1} = I_{B2} = 100 \text{mA}$

Notes: 8. Measured under pulsed conditions. Pulse width \leq 300 μ s. Duty cycle \leq 2%.





Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

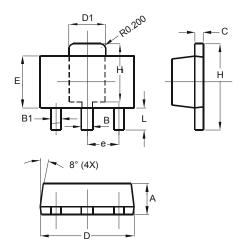






Package Outline Dimensions

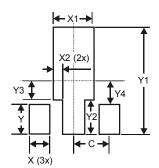
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT89				
Dim	Min	Max		
Α	1.40	1.60		
В	0.44	0.62		
B1	0.35	0.54		
С	0.35	0.44		
D	4.40	4.60		
D1	1.62	1.83		
Е	2.29	2.60		
е	1.50 Typ			
Н	3.94	4.25		
H1	2.63	2.93		
L	0.89	1.20		
All Dimensions in mm				

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
X	0.900
X1	1.733
X2	0.416
Y	1.300
Y1	4.600
Y2	1.475
Y3	0.950
Y4	1.125
С	1.500





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